



# IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

I hereby certify that this transmittal of the below described document is being deposited with the United States Postal Service in an envelope bearing First Class Postage and addressed to the Commissioner for Patents P.O. Box 1450, Alexandria, VA 22313-1450, on the below date of deposit.

Date of Deposit:	08/27/04	Name of Person Making the Deposit:	Shannon Carmo	Signature of the Person Making the Deposit:	<i>Shannon Carmo</i>
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In re Application of: Wenge YANG

Application No.: 09/805,273

Examiner: ESTRADA, Michelle

Filed: 03/13/01

Art Unit: 2823

Confirmation No.: 1234

For: HIGHLY CONDUCTIVE SEMICONDUCTOR STRUCTURES, METHOD OF FORMING SAME VIA PLASMA ETCH, AND ELECTRICAL DEVICES INCORPORATING HIGHLY CONDUCTIVE SEMICONDUCTOR STRUCTERS

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

## AMENDMENT TRANSMITTAL

1. Transmitted herewith is an amendment for this application

☒ Transmitted herewith is a response to an office action for the above identified patent application.  
( 13 sheets)  
Transmitted herewith are \_\_\_\_\_ sheets of substitute formal drawings.  
Other: \_\_\_\_\_

2. Applicant is other than a small entity

## Extension of Term

3. The proceedings herein are for a patent application and the provisions of 37 C.F.R. 1.136 apply.

(a) [ ] Applicant petitions for an extension of time under 37 C.F.R. 1.136  
(fees: 37 C.F.R. 1.17(a)-(d) for the total number of months checked below:)

Extension	Fee
[ ] one month	\$110.00
[ ] two months	\$420.00
[ ] three months	\$950.00
[ ] four months	\$1,480.00

**Fee \$** \_\_\_\_\_

If an additional extension of time is required, please consider this a petition therefor.

(b) [X] Applicant believes that no extension of term is required. However, this conditional petition is being made to provide for the possibility that applicant has inadvertently overlooked the need for a petition for extension of time.

**Fee Calculation**

4. The fee for claims (37 C.F.R. 1.16(b)-(d)) has been calculated as shown below:

<b>(for other than a small entity)</b>					
Fee Items	Claims Remaining After Amendment	Highest Number of Claims Previously Paid For	Present Extra Claims	Fee Rate	Total
Total Claims	21	- 34 =		x \$18.00	\$0.00
Independent Claims	3	- 3 =		x \$86.00	\$0.00
Multiple Dependent Claim Fee (one or more, first added by this amendment)				\$290.00	\$0.00
<b>Total Fees</b>					<b>\$0.00</b>

**PAYMENT OF FEES**

5. The full fee due in connection with this communication is provided as follows:
- ☒ The Commissioner is hereby authorized to charge any additional fees associated with this communication or credit any overpayment to Deposit Account No.: 23-0085.  
A duplicate copy of this authorization is enclosed.
- ☐ A check in the amount of \$
- ☐ Charge any fees required or credit any overpayments associated with this filing to Deposit Account No.: 23-0085.


Please direct all correspondence concerning the above-identified application to the following address:

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Respectfully submitted,

Date: August 27, 2004

By:

  
Eric J. Gash  
Reg. No.: 46,274



GP 2823  
JFW

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application No. : 09/805,273                      Confirmation No. : 1234  
Applicant : YANG, Wenge  
Filed : March 13, 2001  
T.C./A.U. : 2823  
Examiner : ESTRADA, Michelle  
  
Title : Highly Conductive Semiconductor Structures, Method of Forming Same  
Via Plasma Etch, and Electrical Devices Incorporating Highly Conductive  
Semiconductor Structures  
Docket No. : AMD-E365

AMENDMENT AND RESPONSE TO OFFICE ACTION

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

In response to the Office Action of May 27, 2004, Applicant respectfully requests further examination and reconsideration of the above-identified patent application in view of the arguments set forth below.